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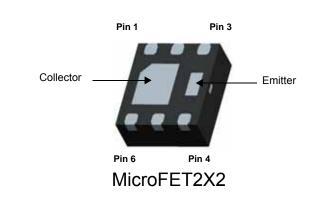
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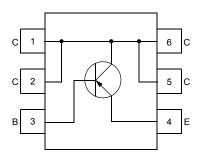


High current surface mount PNP silicon switching transistor for load management in portable applications

- High Collector current
- Low Collector-Emitter Saturation Voltage
- RoHS Compliant







Absolute Maximum Ratings T_a = 25°C unless otherwise noted

| Symbol | Parameter | | Value | Units |
|------------------|---------------------------|-----------------|-------------|--------|
| V _{CBO} | Collector-Base Voltage | | -50 | V |
| V _{CEO} | Collector-Emitter Voltage | | -35 | V |
| V _{EBO} | Emitter-Base Voltage | | -5 | V |
| I _C | Collector Current (DC) | | -2 | A |
| P _D | • | lote1) ote2) | 1.56 0.8 | W W |
| TJ | Junction Temperature | | 150 | °C |
| T _{STG} | Storage Temperature | | -55 ~ 150 | °C |

Thermal Characteristics Ta=25°C unless otherwise noted

| Symbol | Parameter | | Max. | Units |
|----------------|---|------------------|-----------|--------------|
| $R\Theta_{JA}$ | Thermal Resistance, Junction to Ambient | Note1) Note2) | 80 154 | °C/W °C/W |

Note1): The device mounted on a 1inch² pad of 2 oz copper pad on a 1.5×1.5 in. board of FR-4 material. **Note2**): The device mounted on a minimum pad of 2 oz copper pad on a 1.5×1.5 in. board of FR-4 material

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FJMA790 PNP Epitaxial Silicon Transistor

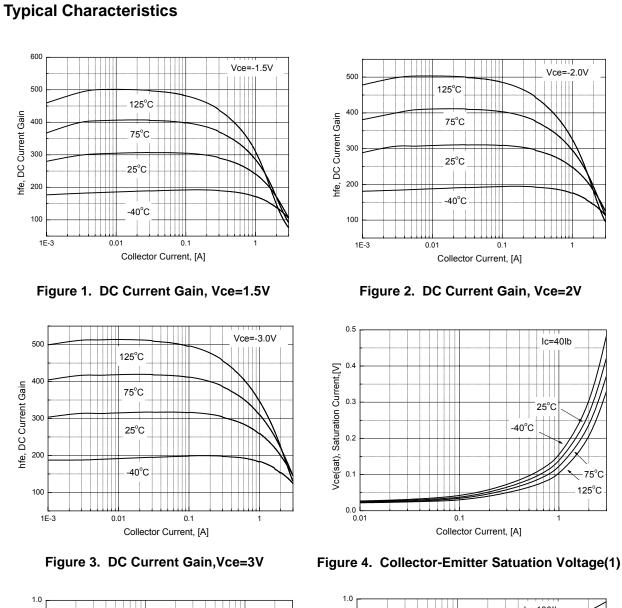
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units |
|----------------------|--------------------------------------|--|--------------------------|------|----------------------|----------------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C = -100μA, I _E = 0 | -50 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = -10mA, I _B = 0 | -35 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_{\rm C}$ = -100µA, $I_{\rm C}$ = 0 | -5 | | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} = -35V, I _C = 0 | | | -0.1 | μA |
| I _{EBO} | Emitter Cut-off Current | $V_{EB} = -4V, I_{C} = 0$ | | | -0.1 | μA |
| h _{FE} | DC Current Gain | | 100 100 100 100 | | 400 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | $I_{C} = -500$ mA, $I_{B} = -5$ mA $I_{C} = -1$ A, $I_{B} = -10$ mA $I_{C} = -2$ A, $I_{B} = -50$ mA | | | -250 -350 -450 | mV mV mV |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = -1A, I _B = -10mA | | | -0.9 | V |
| V _{BE(on)} | Base-Emitter On Voltage | V _{CE} = -2V, I _C = -1A | | | -0.9 | V |

Package Marking and Ordering Information

| ĺ | Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|---|----------------|---------|----------------|-----------|------------|-------------|
| | 790 | FJMA790 | MLP 2×2 Single | 7" | 8mm | 3,000 units |

FJMA790 PNP Epitaxial Silicon Transistor

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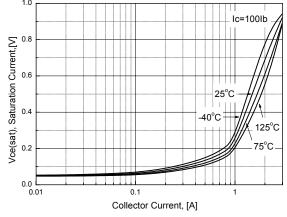


Figure 5. Collector-Emitter Satuation Voltage(2)

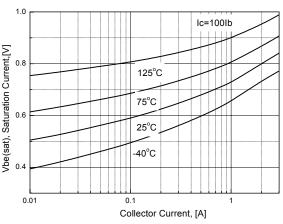


Figure 6. Base-Emitter Saturation Voltage

FJMA790 Rev. A3

FJMA790 PNP Epitaxial Silicon Transistor

Vcb=-35V

100

125

150

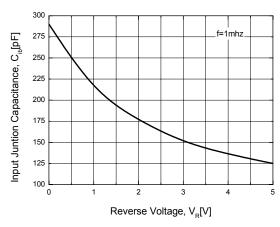
125

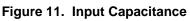
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Typical Performance Characteristics (Continued) 1E-7 Vce=-2V Icbo(A), Reverse Leakage Current 1 1E-8 Emitter Current, [A] 1E-9 75°C 125°C -40°C 25°C 0.1 1E-10 1E-11 0.01 50 25 75 0.4 0.6 0.8 1.0 Ta(°C), Ambent Temperature Vfbe(on), Turn on voltage,[V] Figure 7. Base- Emitter Turn On Voltage Figure 8. Collector-Base Leakage Current 1E-7 2.0 Veb=-4V Icbo(A), Reverse Leakage Current 1E-8 1.5 Pd, Power Dissipation,[W] 1E-9 1.0 0.5 1E-10 0.0 1E-11 25 75 50 100 25 50 75 100 125 0

Ta(°C), Ambent Temperature

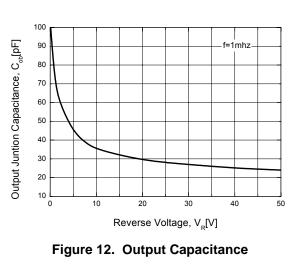


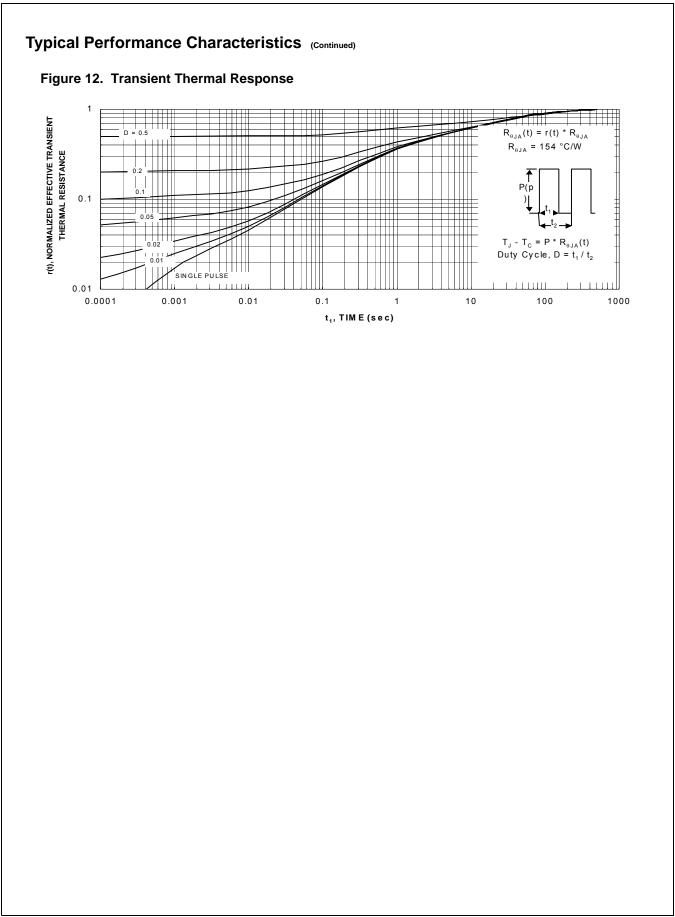




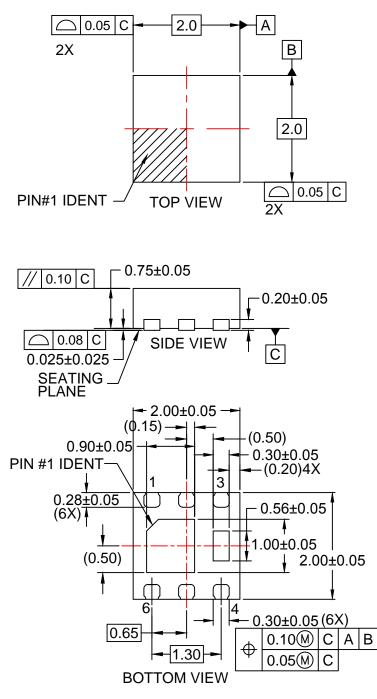


Case Temperature, T [°C]



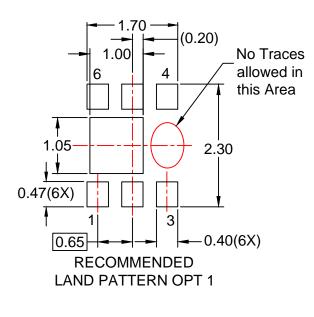


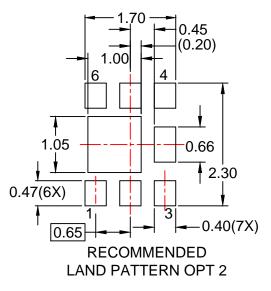
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